

BGA7024

400 MHz to 2700 MHz 0.25 W high linearity silicon amplifier

Rev. 3 — 11 June 2014

Product data sheet

1. Product profile

1.1 General description

The BGA7024 MMIC is a one-stage amplifier, available in a low-cost surface-mount package. It delivers 24 dBm output power at 1 dB gain compression and superior performance up to 2700 MHz.

1.2 Features and benefits

- 400 MHz to 2700 MHz frequency operating range
- 16 dB small signal gain at 2 GHz
- 24 dBm output power at 1 dB gain compression
- Integrated active biasing
- External matching allows broad application optimization of the electrical performance
- 5 V single supply operation
- All pins ESD protected

1.3 Applications

- Broadband CPE/MoCA
- WLAN/ISM/RFID
- Wireless infrastructure (base station, repeater, point-to-point backhaul systems)
- Industrial applications
- E-metering
- Satellite Master Antenna TV (SMATV)

1.4 Quick reference data

Table 1. Quick reference data

Input and output impedances matched to 50 Ω . Typical values at V_{CC} = 5 V; T_{case} = 25 $^{\circ}$ C; unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{CC}	supply current			95	110	125	mΑ
f	frequency		[1]	400	-	2700	MHz
Gp	power gain	f = 2140 MHz		13.5	15	16.5	dB
P _{L(1dB)}	output power at 1 dB gain compression	f = 2140 MHz		24.0	25.5	-	dBm
IP3 _O	output third-order intercept point	f = 2140 MHz	[2]	35.0	38.5	-	dBm

^[1] Operation outside this range is possible but not guaranteed.



^[2] $P_L = 11$ dBm per tone; spacing = 1 MHz.

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2. Pinning information

Table 2. Pinning

Pin	Description		Simplified outline	Graphic symbol
1	V _{CC(RF)}	<u>[1]</u>		_
2	GND	[2]		31
3	RF_IN	<u>[1]</u>	3 2 1	2 /// sym130

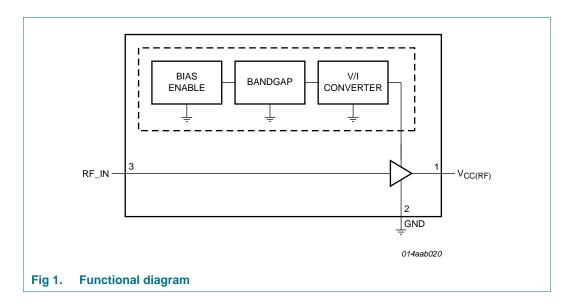
- [1] This pin is DC-coupled and requires an external DC-blocking capacitor.
- [2] The center metal base of the SOT89 also functions as heatsink for the power amplifier.

3. Ordering information

Table 3. Ordering information

Type number	Package								
	Name	Description	Version						
BGA7024	-	plastic surface-mounted package; exposed die pad for good heat transfer; 3 leads	SOT89						

4. Functional diagram



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5. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC(RF)}	RF supply voltage		-	5.7	V
P _{i(RF)}	RF input power		-	25	dBm
T _{case}	case temperature		-40	+85	°C
Tj	junction temperature		-	150	°C
V _{ESD}	electrostatic discharge voltage	Human Body Model (HBM); according to JEDEC standard 22-A114E	-	2000	V
		Charged Device Model (CDM); according to JEDEC standard 22-C101B	-	500	V

6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	[1][2]	25	K/W

^[1] Case is ground solder pad.

7. Static characteristics

Table 6. Characteristics

Input and output impedances matched to 50 Ω . Typical values at $V_{CC} = 5$ V; $T_{case} = 25$ °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		-	5.0	-	V
I _{CC}	supply current		95	110	125	mA

8. Dynamic characteristics

Table 7. Dynamic characteristics

Input and output impedances matched to 50 Ω . Typical values at $V_{CC} = 5 \text{ V}$; $T_{case} = 25 \text{ °C}$; see Section 12 "Application information"; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
f	frequency	[1]	400	-	2700	MHz
Gp	power gain	f = 940 MHz	-	22	-	dB
		f = 1960 MHz	-	16	-	dB
		f = 2140 MHz	13.5	15	16.5	dB
		f = 2445 MHz	-	14	-	dB

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^[2] Thermal resistance measured using infrared measurement technique, device mounted on application board and placed in still air.

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Table 7. Dynamic characteristics ...continued Input and output impedances matched to 50 Ω . Typical values at $V_{CC} = 5 \text{ V}$; $T_{case} = 25 \text{ °C}$; see Section 12 "Application information"; unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
P _{L(1dB)}	output power at 1 dB gain compression	f = 940 MHz		-	24	-	dBm
		f = 1960 MHz		-	25.5	-	dBm
		f = 2140 MHz		24.0	25.5	-	dBm
		f = 2445 MHz		-	24.5	-	dBm
IP3 _O	output third-order intercept point	f = 940 MHz	[2]	-	37.5	-	dBm
		f = 1960 MHz	[2]	-	38.0	-	dBm
		f = 2140 MHz	[2]	35.0	38.0	-	dBm
		f = 2445 MHz	[2]	-	37.5	-	dBm
NF	noise figure	f = 940 MHz	[3]	-	2.9	-	dB
		f = 1960 MHz	[3]	-	3.7	-	dB
		f = 2140 MHz	[3]	-	3.7	-	dB
		f = 2445 MHz	[3]	-	4.0	-	dB
RLin	input return loss	f = 940 MHz		-	-9	-	dB
		f = 1960 MHz		-	-10	-	dB
		f = 2140 MHz		-	-10	-	dB
		f = 2445 MHz		-	-14	-	dB
RLout	output return loss	f = 940 MHz		-	-29	-	dB
		f = 1960 MHz		-	-22	-	dB
		f = 2140 MHz		-	-29	-	dB
		f = 2445 MHz		-	-11	-	dB

^[1] Operation outside this range is possible but not guaranteed.

9. Scattering parameters

Table 8. Scattering parameters at 5 V, MMIC only

f (MHz)	S ₁₁	S ₁₁		S_{21} S_{12} S_{22}		S ₁₂		
	Magnitude (ratio)	Angle (degree)	Magnitude (ratio)	Angle (degree)	Magnitude (ratio)	Angle (degree)	Magnitude (ratio)	Angle (degree)
400	0.83	-178.9	14.03	112.7	0.01	35.5	0.53	-166.3
500	0.85	178.7	11.69	104.4	0.01	38.77	0.56	-168.9
600	0.85	176.4	9.93	98.19	0.02	41.13	0.57	-172.2
700	0.86	173.8	8.67	93.04	0.02	43.1	0.58	-174.8
800	0.86	171.1	7.68	88.54	0.02	44.34	0.58	-177.4
900	0.86	168.3	6.9	84.36	0.02	44.96	0.59	179.7
1000	0.86	165.4	6.29	80.24	0.02	45.07	0.60	176.7
1100	0.87	162.7	5.72	76.42	0.02	45	0.60	173.3
1200	0.88	159.9	5.23	72.83	0.02	44.54	0.60	170.9
1300	0.88	157.3	4.80	69.34	0.03	44.17	0.61	168.4

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^[2] $P_L = 11$ dBm per tone; spacing = 1 MHz.

^[3] Defined at $P_{i(RF)} = -40$ dBm; small signal conditions.

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 Table 8.
 Scattering parameters at 5 V, MMIC only ...continued

f (MHz)	S ₁₁	11			S ₁₂		S ₂₂	
	Magnitude (ratio)	Angle (degree)	Magnitude (ratio)	Angle (degree)	Magnitude (ratio)	Angle (degree)	Magnitude (ratio)	Angle (degree)
1400	0.89	154.8	4.43	66.17	0.03	43.58	0.61	166.4
1500	0.89	153	4.09	63.33	0.03	43.02	0.62	164.7
1600	0.89	151.3	3.80	60.8	0.03	42.67	0.63	163.1
1700	0.90	149.9	3.54	58.3	0.03	42.36	0.64	162.1
1800	0.90	148.7	3.30	56.13	0.03	41.89	0.65	161.2
1900	0.90	147.9	3.11	54.13	0.03	41.65	0.66	160.8
2000	0.91	147.5	2.93	52.63	0.03	41.7	0.66	160.5
2100	0.90	147	2.78	50.91	0.04	41.61	0.66	160.5
2200	0.90	146.9	2.65	49.5	0.04	41.59	0.67	160.9
2300	0.90	146.6	2.54	48.13	0.04	41.44	0.66	161.6
2400	0.90	146.5	2.46	46.88	0.04	41.61	0.66	161.7
2500	0.89	146.3	2.39	45.39	0.04	41.45	0.66	162.6
2600	0.88	146	2.34	43.93	0.05	41.13	0.65	162.8
2700	0.87	145.4	2.30	42.24	0.05	40.56	0.64	163.2

10. Reliability information

Table 9. Reliability

Life test	Conditions	Intrinsic failure rate
HTOL	according to JESD85; confidence level 60 %; T_j = 55 °C; activation energy = 0.7 eV; acceleration factor according to Arrhenius equation	4

11. Moisture sensitivity

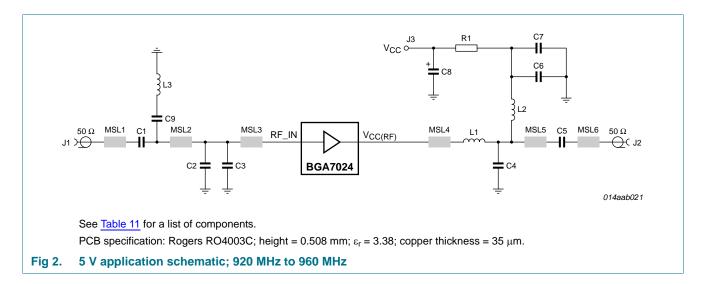
Table 10. Moisture sensitivity level

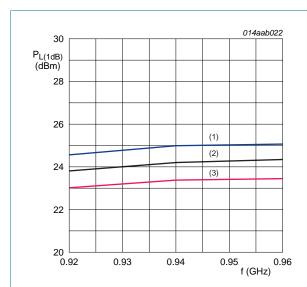
Test methodology	Class
JESD-22-A113	1

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12. Application information

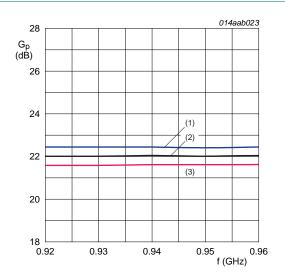
12.1 920 MHz to 960 MHz





- (1) $T_{case} = -40 \, ^{\circ}C$.
- (2) $T_{case} = 25 \, ^{\circ}C$.
- (3) $T_{case} = 85 \, ^{\circ}C$.

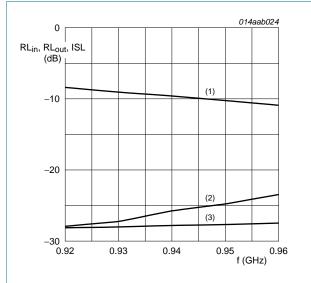
Fig 3. Output power at 1 dB gain compression as a function of frequency



- (1) $T_{case} = -40 \, ^{\circ}C$.
- (2) $T_{case} = 25 \, ^{\circ}C$.
- (3) $T_{case} = 85 \, ^{\circ}C$.

Fig 4. Power gain as a function of frequency

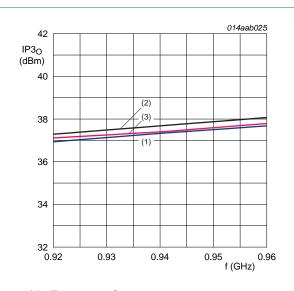
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T_{case} = 25 °C.

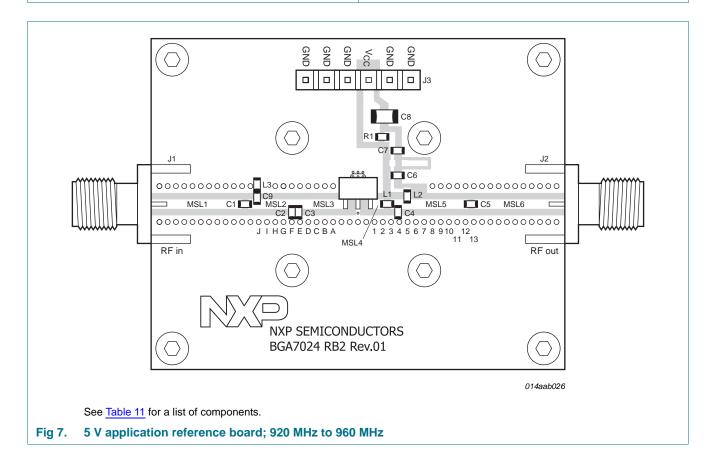
- (1) RL_{in}
- (2) RL_{out}
- (3) ISL

Fig 5. Input return loss, output return loss and isolation as a function of frequency



- (1) $T_{case} = -40 \, ^{\circ}C$.
- (2) $T_{case} = 25 \, ^{\circ}C$.
- (3) $T_{case} = 85 \, ^{\circ}C$.

Fig 6. Output third-order intercept point as a function of frequency



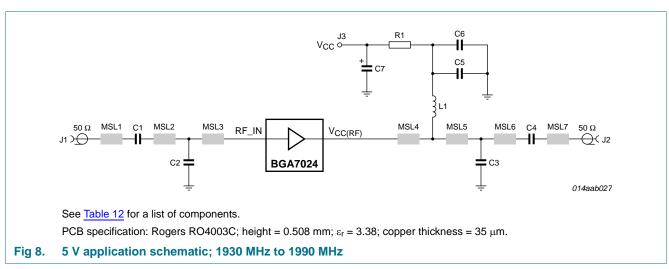
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Table 11. 5 V application list of components; 920 MHz to 960 MHz See <u>Figure 2</u> and <u>Figure 7</u> for component layout. PCB: Rogers RO4003C stack; height = 0.508 mm; copper plating thickness = $35 \mu m$.

Component	Description	Value	Function	Remarks
C1, C5	capacitor	68 pF	DC blocking	Murata GRM1885C1H680JA01D
C2	capacitor	3.9 pF	input match Murata GRM1885C1H3R9CZ0	
C3	capacitor	3.9 pF	input match	Murata GRM1885C1H3R9CZ01D
C4	capacitor	3.9 pF	output match	Murata GRM1885C1H3R9CZ01D
C6	capacitor	68 pF	RF decoupling	Murata GRM1885C1H680JA01D
C7	capacitor	100 nF	DC decoupling	AVX 0603YC104KAT2A
C8	capacitor	10 μF	DC decoupling	AVX 1206ZG106ZAT2A
C9	capacitor	68 nF	IMD suppression	Murata GRM1888R71H683KA93D
J1, J2	RF connector	SMA	-	Emerson Network Power 142-0701-841
J3	DC connector	6-pins	-	MOLEX
L1	inductor	4.7 nH	output match	Tyco Electronics 36501J4N7JTDG
L2	inductor	22 nH	DC feed	Tyco Electronics 36501J022JTDG
L3	inductor	33 nH	IMD suppression	Tyco Electronics 36501J033JTDG
MSL1[1]	micro stripline	1.14 mm × 0.8 mm × 10.95 mm	input match	-
MSL2[1]	micro stripline	1.14 mm × 0.8 mm × 5.65 mm	input match	-
MSL3[1]	micro stripline	1.14 mm × 0.8 mm × 6.1 mm	input match	-
MSL4[1]	micro stripline	1.14 mm × 0.8 mm × 1.6 mm	output match	-
MSL5[1]	micro stripline	1.14 mm × 0.8 mm × 8.4 mm	output match	-
MSL6[1]	micro stripline	1.14 mm × 0.8 mm × 10.95 mm	output match	-
R1	resistor	0 Ω	-	Multicomp MC 0.063W 0603 0R
PCB	-	RO4003C	-	-

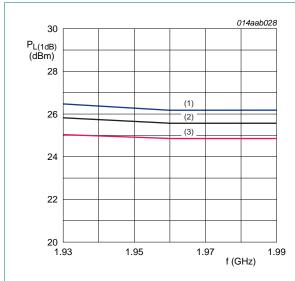
^[1] MSL1 to MSL6 dimensions specified as width \times spacing \times length.

12.2 1930 MHz to 1990 MHz



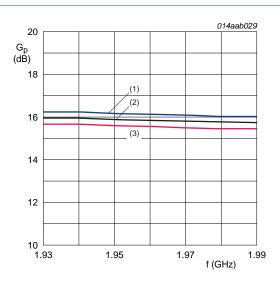
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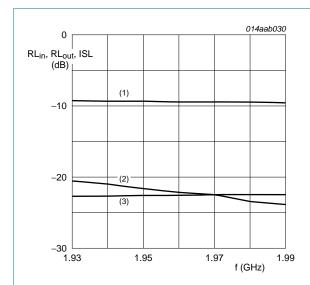
- (1) $T_{case} = -40 \, ^{\circ}C$.
- (2) $T_{case} = 25 \, ^{\circ}C$.
- (3) $T_{case} = 85 \, ^{\circ}C$.

Fig 9. Output power at 1 dB gain compression as a function of frequency



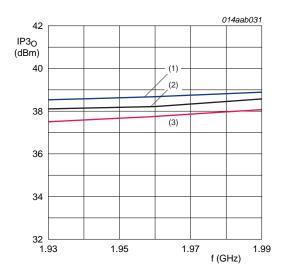
- (1) $T_{case} = -40 \, ^{\circ}C$.
- (2) $T_{case} = 25 \, ^{\circ}C$.
- (3) $T_{case} = 85 \, ^{\circ}C$.

Fig 10. Power gain as a function of frequency



- $T_{case} = 25 \, ^{\circ}C.$
- (1) RL_{in}
- (2) RL_{out}
- (3) ISL

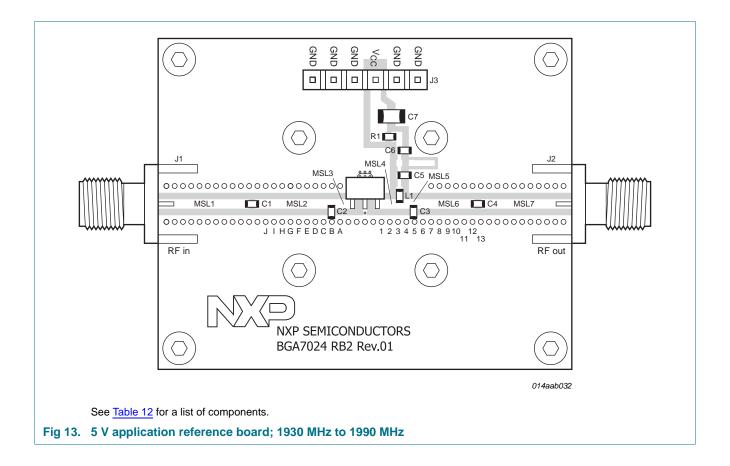
Fig 11. Input return loss, output return loss and isolation as a function of frequency



- (1) $T_{case} = -40 \, ^{\circ}C$.
- (2) $T_{case} = 25 \, ^{\circ}C$.
- (3) $T_{case} = 85 \, ^{\circ}C$.

Fig 12. Output third-order intercept point as a function of frequency

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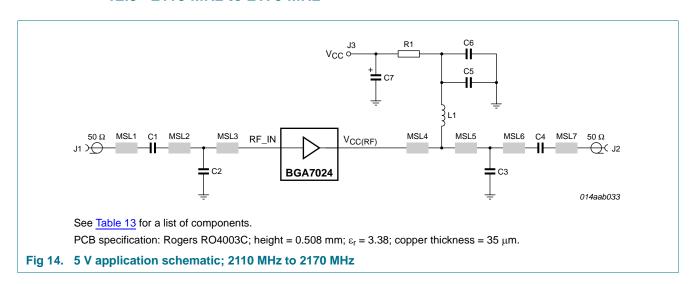
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Table 12. 5 V application list of components; 1930 MHz to 1990 MHz See <u>Figure 8</u> and <u>Figure 13</u> for component layout. PCB: Rogers RO4003C stack; height = 0.508 mm; copper plating thickness = $35 \mu m$.

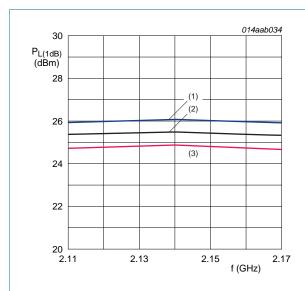
Component	Description	Value	Function	Remarks
C1, C4	capacitor	15 pF	DC blocking	Murata GRM1885C1H150JA01D
C2	capacitor	2.4 pF	input match	Murata GRM1885C1H2R4CZ01D
C3	capacitor	1.5 pF	output match	Murata GRM1885C1H1R5CZ01D
C5	capacitor	15 pF	RF decoupling	Murata GRM1885C1H150JA01D
C6	capacitor	100 nF	DC decoupling	AVX 0603YC104KAT2A
C7	capacitor	10 μF	DC decoupling	AVX 1206ZG106ZAT2A
J1, J2	RF connector	SMA	-	Emerson Network Power 142-0701-841
J3	DC connector	6-pins	-	MOLEX
L1	inductor	22 nH	DC feed	Tyco Electronics 36501J022JTDG
MSL1 ¹¹	micro stripline	1.14 mm × 0.8 mm × 10.95 mm	input match	-
MSL2[1]	micro stripline	1.14 mm × 0.8 mm × 10.6 mm	input match	-
MSL3[1]	micro stripline	1.14 mm × 0.8 mm × 1.0 mm	input match	-
MSL4[1]	micro stripline	1.14 mm × 0.8 mm × 2.7 mm	output match	-
MSL5[1]	micro stripline	1.14 mm × 0.8 mm × 3.2 mm	output match	-
MSL6[1]	micro stripline	1.14 mm × 0.8 mm × 5.5 mm	output match	-
MSL7[1]	micro stripline	1.14 mm × 0.8 mm × 10.95 mm	output match	-
R1	resistor	0 Ω	-	Multicomp MC 0.063W 0603 0R
PCB	-	RO4003C	-	-

^[1] MSL1 to MSL7 dimensions specified as width \times spacing \times length.

12.3 2110 MHz to 2170 MHz

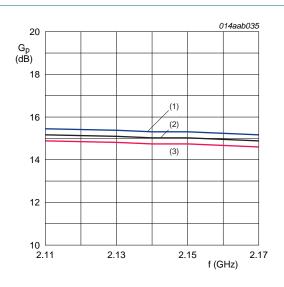


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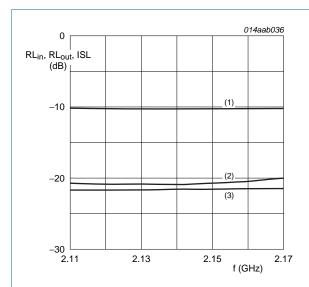
- (1) $T_{case} = -40 \, ^{\circ}C$.
- (2) $T_{case} = 25 \, ^{\circ}C$.
- (3) $T_{case} = 85 \, ^{\circ}C$.

Fig 15. Output power at 1 dB gain compression as a function of frequency



- (1) $T_{case} = -40 \, ^{\circ}C$.
- (2) $T_{case} = 25 \, ^{\circ}C$.
- (3) $T_{case} = 85 \, ^{\circ}C$.

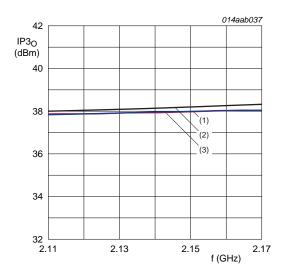
Fig 16. Power gain as a function of frequency



 $T_{case} = 25 \, ^{\circ}C.$

- (1) RL_{in}
- (2) RL_{out}
- (3) ISL

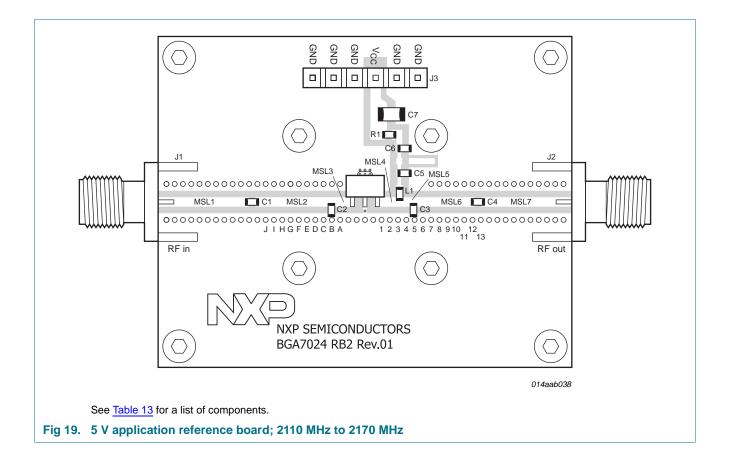
Fig 17. Input return loss, output return loss and isolation as a function of frequency



- (1) $T_{case} = -40 \, ^{\circ}C$.
- (2) $T_{case} = 25 \, ^{\circ}C$.
- (3) $T_{case} = 85 \, ^{\circ}C$.

Fig 18. Output third-order intercept point as a function of frequency

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400 MHz to 2700 MHz 0.25 W high linearity silicon amplifier

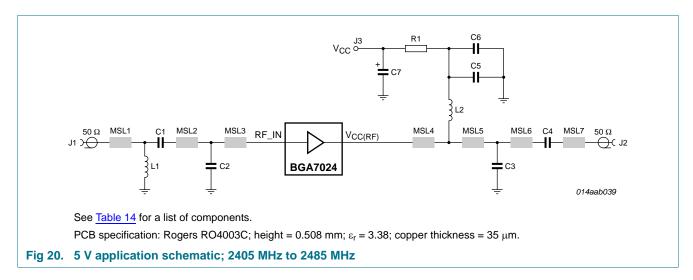
Table 13. 5 V application list of components; 2110 MHz to 2170 MHz

See <u>Figure 14</u> and <u>Figure 19</u> for component layout. PCB: Rogers RO4003C stack; height = 0.508 mm; copper plating thickness = $35 \mu m$.

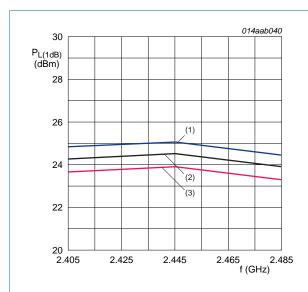
Component	Description	Value	Function	Remarks
C1, C4	capacitor	15 pF	DC blocking	Murata GRM1885C1H150JA01D
C2	capacitor	2.2 pF	input match	Murata GRM1885C1H2R2CZ01D
C3	capacitor	1.5 pF	output match	Murata GRM1885C1H1R5CZ01D
C5	capacitor	15 pF	RF decoupling	Murata GRM1885C1H150JA01D
C6	capacitor	100 nF	DC decoupling	AVX 0603YC104KAT2A
C7	capacitor	10 μF	DC decoupling	AVX 1206ZG106ZAT2A
J1, J2	RF connector	SMA	-	Emerson Network Power 142-0701-841
J3	DC connector	6-pins	-	MOLEX
L1	inductor	22 nH	DC feed	Tyco Electronics 36501J022JTDG
MSL1 ¹¹	micro stripline	1.14 mm × 0.8 mm × 10.95 mm	input match	-
MSL2[1]	micro stripline	1.14 mm × 0.8 mm × 10.6 mm	input match	-
MSL3[1]	micro stripline	1.14 mm × 0.8 mm × 1.0 mm	input match	-
MSL4[1]	micro stripline	1.14 mm × 0.8 mm × 2.7 mm	output match	-
MSL5[1]	micro stripline	1.14 mm × 0.8 mm × 3.2 mm	output match	-
MSL6[1]	micro stripline	1.14 mm × 0.8 mm × 5.5 mm	output match	-
MSL7[1]	micro stripline	1.14 mm × 0.8 mm × 10.95 mm	output match	-
R1	resistor	0 Ω	-	Multicomp MC 0.063W 0603 0R
PCB	-	RO4003C	-	-

^[1] MSL1 to MSL7 dimensions specified as width \times spacing \times length.

12.4 2405 MHz to 2485 MHz

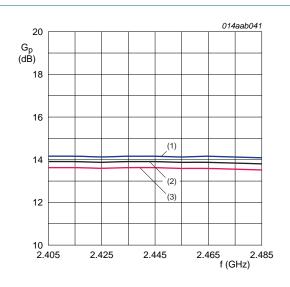


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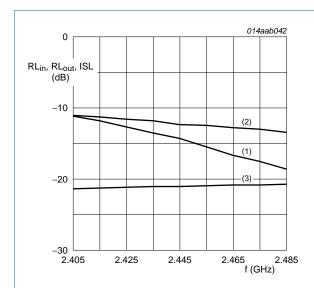
- (1) $T_{case} = -40 \, ^{\circ}C$.
- (2) $T_{case} = 25 \, ^{\circ}C$.
- (3) $T_{case} = 85 \, ^{\circ}C$.

Fig 21. Output power at 1 dB gain compression as a function of frequency



- (1) $T_{case} = -40 \, ^{\circ}C$.
- (2) $T_{case} = 25 \, ^{\circ}C$.
- (3) $T_{case} = 85 \, ^{\circ}C$.

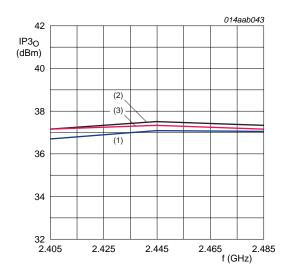
Fig 22. Power gain as a function of frequency



 $T_{case} = 25 \, ^{\circ}C.$

- (1) RL_{in}
- (2) RL_{out}
- (3) ISL

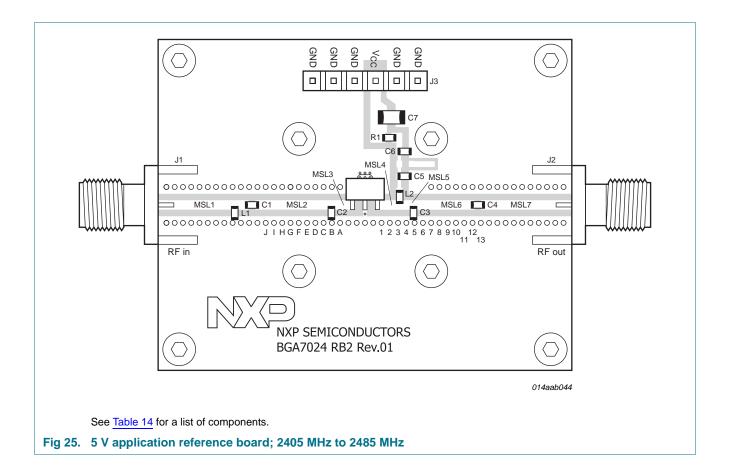
Fig 23. Input return loss, output return loss and isolation as a function of frequency



- (1) $T_{case} = -40 \, ^{\circ}C$.
- (2) $T_{case} = 25 \, ^{\circ}C$.
- (3) $T_{case} = 85 \, ^{\circ}C$.

Fig 24. Output third-order intercept point as a function of frequency

400 MHz to 2700 MHz 0.25 W high linearity silicon amplifier



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Table 14. 5 V application list of components; 2405 MHz to 2485 MHz

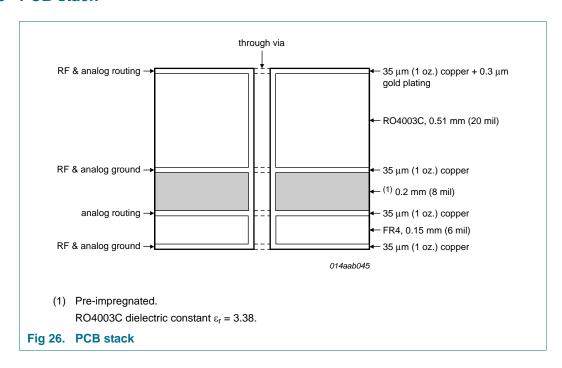
See <u>Figure 20</u> and <u>Figure 25</u> for component layout. PCB: Rogers RO4003C stack; height = 0.508 mm; copper plating thickness = $35 \mu m$.

Component	Description	Value	Function	Remarks
C1, C4	capacitor	15 pF	DC blocking	Murata GRM1885C1H150JA01D
C2	capacitor	1.5 pF	input match	Murata GRM1885C1H1R5CZ01D
C3	capacitor	1.8 pF	output match	Murata GRM1885C1H1R8CZ01D
C5	capacitor	15 pF	RF decoupling	Murata GRM1885C1H150JA01D
C6	capacitor	100 nF	DC decoupling	AVX 0603YC104KAT2A
C7	capacitor	10 μF	DC decoupling	AVX 1206ZG106ZAT2A
J1, J2	RF connector	SMA	-	Emerson Network Power 142-0701-841
J3	DC connector	6-pins	-	MOLEX
L1	inductor	3.3 nH	input match	Tyco Electronics 36501J3N3JTDG
L2	inductor	22 nH	DC feed	Tyco Electronics 36501J022JTDG
MSL1 ¹¹	micro stripline	1.14 mm × 0.8 mm × 10.95 mm	input match	-
MSL2[1]	micro stripline	1.14 mm × 0.8 mm × 9.8 mm	input match	-
MSL3[1]	micro stripline	1.14 mm × 0.8 mm × 1.9 mm	output match	-
MSL4[1]	micro stripline	1.14 mm × 0.8 mm × 2.5 mm	output match	-
MSL5[1]	micro stripline	1.14 mm × 0.8 mm × 1.6 mm	output match	-
MSL6[1]	micro stripline	1.14 mm × 0.8 mm × 7.3 mm	output match	-
MSL7[1]	micro stripline	1.14 mm × 0.8 mm × 10.95 mm	output match	-
R1	resistor	0 Ω	-	Multicomp MC 0.063W 0603 0R
PCB	-	RO4003C	-	-

^[1] MSL1 to MSL7 dimensions specified as width \times spacing \times length.

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12.5 PCB stack



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13. Package outline

Plastic surface-mounted package; exposed die pad for good heat transfer; 3 leads

SOT89

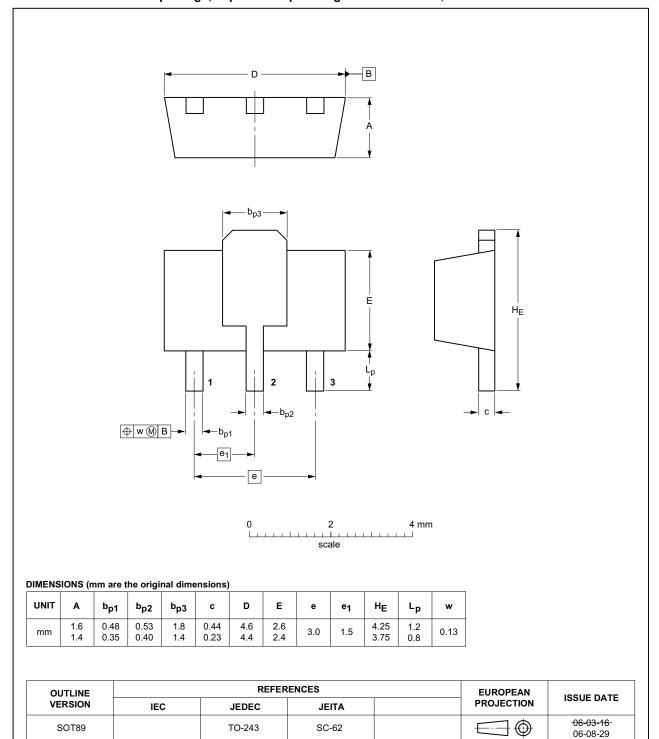


Fig 27. Package outline SOT89

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14. Abbreviations

Table 15. Abbreviations

Acronym	Description
CPE	Customer-Premises Equipment
ESD	ElectroStatic Discharge
HTOL	High Temperature Operating Life
IR	InfraRed
ISM	Industrial, Scientific and Medical
MMIC	Monolithic Microwave Integrated Circuit
MoCA	Multimedia over Coax Alliance
PCB	Printed-Circuit Board
RFID	Radio Frequency IDentification
TX	Transmit
WLAN	Wireless Local Area Network

15. Revision history

Table 16. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BGA7024 v.3	20140611	Product data sheet	-	BGA7024 v.2
Modifications:	• Table 5 on page 3:	Thermal simulation results have b	peen replaced by IR measur	ements results.
BGA7024 v.2	20100830	Product data sheet	-	BGA7024 v.1
BGA7024	20100528	Product data sheet	-	-

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16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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